

Bipolar Transistors Silicon NPN/PNP Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

## **RN4986FE**

#### 1. Applications

- · Switching
- · Inverter Circuits
- · Interfacing
- · Driver Circuits

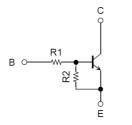
#### 2. Features

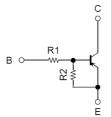
- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) Small package (Dual type)
- (3) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.

#### 3. Equivalent Circuit

Q1

Q2



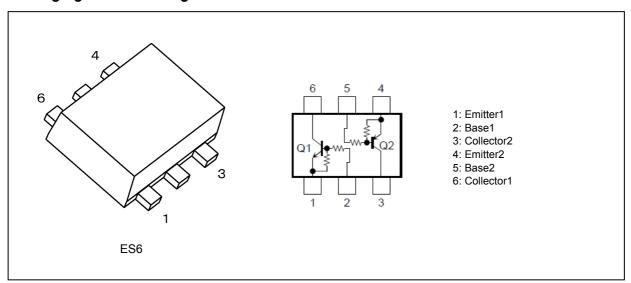


R1:  $4.7 \text{ k}\Omega$ 

R2: 47 kΩ

(Q1, Q2 common)

#### 4. Packaging and Pin Assignment



Start of commercial production

2000-05



#### 5. Orderable part number

Orderable part number	AEC-Q101 Note		Note		
RN4986FE,LF	_		General Use		
RN4986FE,LXGF	YES	(Note 1)	Unintended Use (Note 1)		
RN4986FE,LXHF	YES		Automotive Use		

Note 1: For more information, please contact our sales or use the inquiry form on our website.

#### 6. Q1 Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	
Emitter-base voltage	V <sub>EBO</sub>	5	
Collector current	I <sub>C</sub>	100	mA

## 7. Q2 Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	
Emitter-base voltage	V <sub>EBO</sub>	-5	
Collector current	I <sub>C</sub>	-100	mA

# 8. Q1, Q2 Common Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Rating	Unit	
Collector power dissipation	(Note 1)	P <sub>C</sub>	100	mW
Junction temperature		T <sub>j</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

#### 9. Q1 Electrical Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0 mA	_	_	100	nA
Collector cut-off current	I <sub>CEO</sub>	$V_{CE} = 50 \text{ V}, I_{B} = 0 \text{ mA}$	_	_	500	
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0 mA	0.074	_	0.138	mA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA	80	-	_	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0.25 mA	_	0.1	0.3	V
Input voltage (ON)	V <sub>I(ON)</sub>	$V_{CE} = 0.2 \text{ V, } I_{C} = 5 \text{ mA}$	0.7	_	1.3	
Input voltage (off)	$V_{I(off)}$	$V_{CE} = 5 \text{ V}, I_{C} = 0.1 \text{ mA}$	0.5	-	0.8	
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA	_	250	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	_	3	6	pF

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2021-08-18



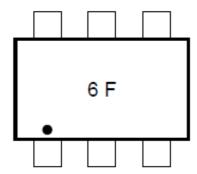
## 10. Q2 Electrical Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_{E} = 0 \text{ mA}$	_	_	-100	nA
Collector cut-off current	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_{B} = 0 \text{ mA}$	_	_	-500	
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V, } I_{C} = 0 \text{ mA}$	-0.074	_	-0.138	mA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -10 mA	80	-	_	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = -5 mA, I <sub>B</sub> = -0.25 mA	_	-0.1	-0.3	V
Input voltage (ON)	V <sub>I(ON)</sub>	$V_{CE}$ = -0.2 V, $I_{C}$ = -5 mA	-0.7	_	-1.3	
Input voltage (off)	V <sub>I(off)</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -0.1 mA	-0.5	_	-0.8	
Transition frequency	f <sub>T</sub>	$V_{CE}$ = -10 V, $I_{C}$ = -5 mA	_	200	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	_	3	6	pF

## 11. Q1, Q2 Common Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input resistance	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ
Resistor ratio	R1/R2	-	0.09	0.1	0.11	_

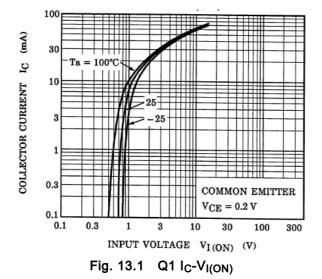
## 12. Marking

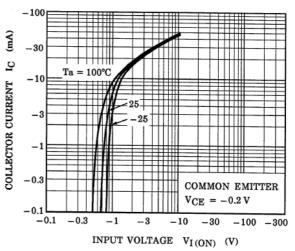




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#### 13. Characteristics Curves (Note)





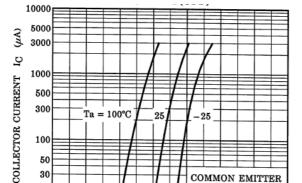
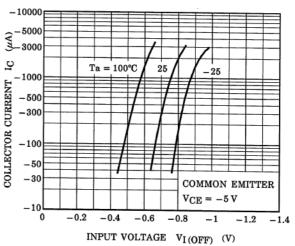
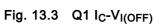


Fig. 13.2 Q2 I<sub>C</sub>-V<sub>I(ON)</sub>





INPUT VOLTAGE V<sub>I (OFF)</sub> (V)

COMMON EMITTER

1.2

 $V_{CE} = 5 V$ 

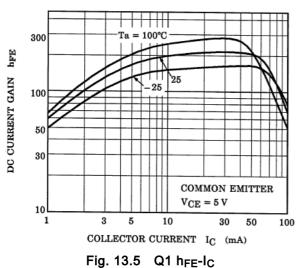


Fig. 13.4 Q2 I<sub>C</sub>-V<sub>I(OFF)</sub>

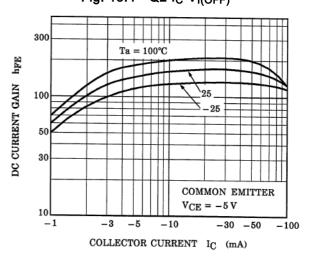


Fig. 13.6 Q2 h<sub>FE</sub>-I<sub>C</sub>



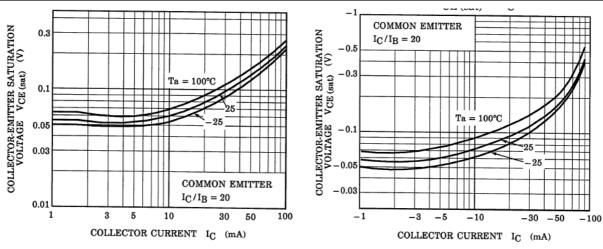


Fig. 13.7 Q1 V<sub>CE(sat)</sub>-I<sub>C</sub>

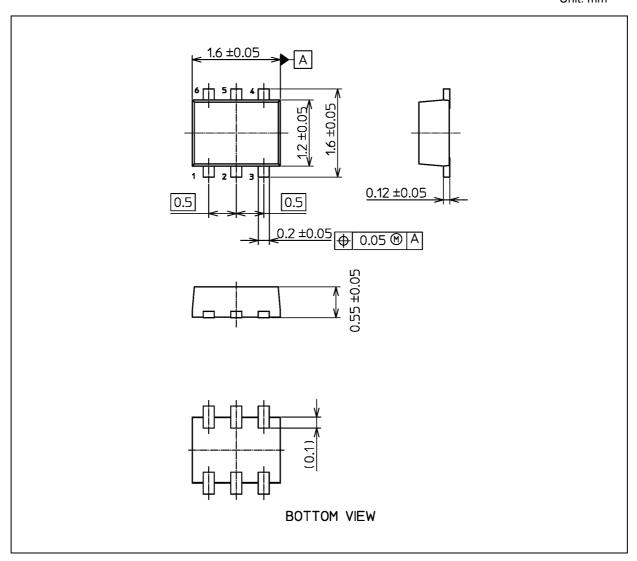
Fig. 13.8 Q2 V<sub>CE(sat)</sub>-I<sub>C</sub>

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 3.0 mg (typ.)

	Package Name(s)
TOSHIBA: 1-2X1S	
Nickname: ES6	



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